

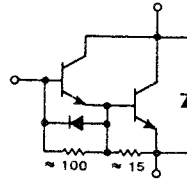
SWITCHMODE SERIES

NPN SILICON POWER DARLINGTON TRANSISTORS WITH BASE-EMITTER SPEEDUP DIODE

The MJ10020 and MJ10021 darlington transistors are designed for high-voltage, high-speed, power switching in inductive circuits where fall time is critical. They are particularly suited for line operated switchmode applications such as:

FEATURES:

- *Continuous Collector Current - $I_C = 60$ A
- *Switching Regulators
- *Inverters
- *Solenoid and Relay Drivers
- *AC and DC Motor Controls

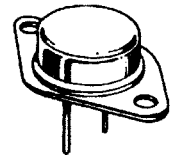


NPN
MJ10020
MJ10021

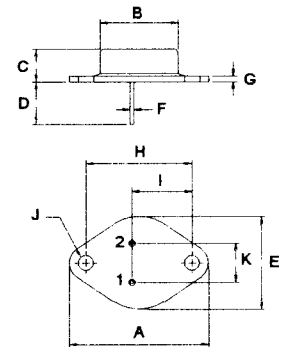
60 AMPERE
POWER DARLINGTON
TRANSISTORS
200-250 VOLTS
250 WATTS

MAXIMUM RATINGS

Characteristic	Symbol	MJ10020	MJ10021	Unit
Collector-Emitter Voltage	V_{CEV}	200	250	V
Collector-Emitter Voltage	$V_{CEO(SUS)}$	300	350	V
Emitter-Base Voltage	V_{EBO}	8.0		V
Collector Current-Continuous -Peak	I_C I_{CM}	60 100		A
Base current	I_B	20		A
Total Power Dissipation @ $T_C = 25^\circ C$ Derate above $25^\circ C$ @ $T_C = 100^\circ C$	P_D	250 143 1.43		W W W/ $^\circ C$
Operating and Storage Junction Temperature Range	T_J, T_{STG}	- 65 to +200		$^\circ C$



TO-3

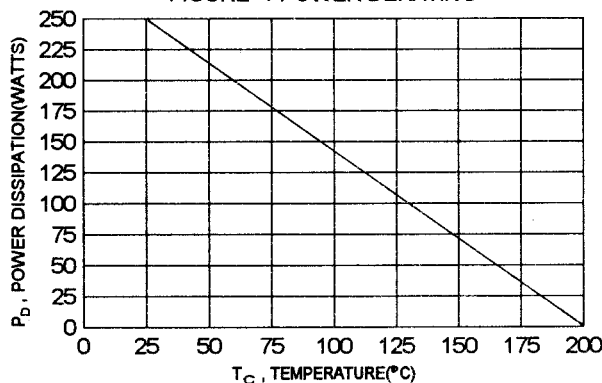


PIN 1.BASE
2.EMITTER
COLLECTOR(CASE)

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	0.7	$^\circ C/W$

FIGURE -1 POWER DERATING



DIM	MILLIMETERS	
	MIN	MAX
A	38.75	39.96
B	19.28	22.23
C	7.96	9.28
D	11.18	12.19
E	25.20	26.67
F	1.46	1.55
G	1.38	1.62
H	29.90	30.40
I	16.64	17.30
J	3.88	4.36
K	10.67	11.18

ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
----------------	--------	-----	-----	------

OFF CHARACTERISTICS

Collector - Emitter Sustaining Voltage ($I_C = 100\text{ mA}, I_B = 0$)	MJ10020 MJ10021 $V_{CEO(sus)}$	200 250		V
Collector Cutoff Current ($V_{CEV} = \text{Rated Value}, V_{BE(OFF)} = 1.5\text{ V}$) ($V_{CEV} = \text{Rated Value}, V_{BE(OFF)} = 1.5\text{ V}, T_C = 150^\circ\text{C}$)	I_{CEV}		0.25 5.0	mA
Collector Cutoff Current ($V_{CEV} = \text{Rated Value}, V_{CEV}, R_{BE} = 50\ \Omega, T_C = 100^\circ\text{C}$)	I_{CER}		5.0	mA
Emitter Cutoff Current ($V_{EB} = 2.0\text{ V}, I_C = 0$)	I_{EBO}		175	mA

ON CHARACTERISTICS (1)

DC Current Gain ($I_C = 15\text{ A}, V_{CE} = 5.0\text{ V}$)	h_{FE}	75	1000	
Collector - Emitter Saturation Voltage ($I_C = 30\text{ A}, I_B = 1.2\text{ A}$) ($I_C = 60\text{ A}, I_B = 4.0\text{ A}$) ($I_C = 30\text{ A}, I_B = 1.2\text{ A}, T_C = 100^\circ\text{C}$)	$V_{CE(sat)}$		2.2 4.0 2.4	V
Base - Emitter Saturation Voltage ($I_C = 30\text{ A}, I_B = 1.2\text{ A}$) ($I_C = 30\text{ A}, I_B = 1.2\text{ A}, T_C = 100^\circ\text{C}$)	$V_{BE(sat)}$		3.0 3.5	V
Diode Forward Voltage ($I_F = 30\text{ A}$)	V_F		5.0	V

DYNAMIC CHARACTERISTICS

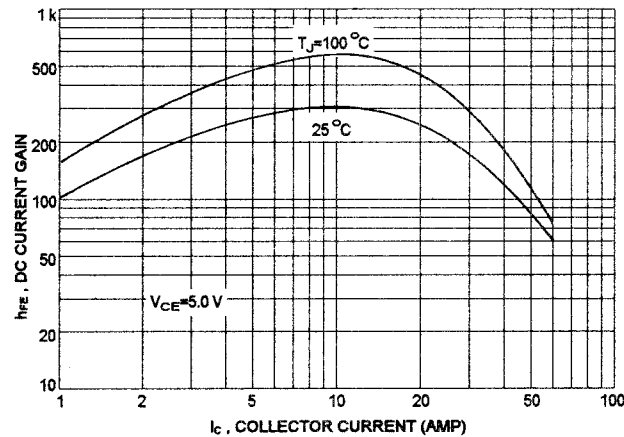
Output Capacitance ($V_{CB} = 10\text{ V}, I_E = 0, f = 1.0\text{ kHz}$)	C_{ob}	160	750	pF
---	----------	-----	-----	----

SWITCHING CHARACTERISTICS

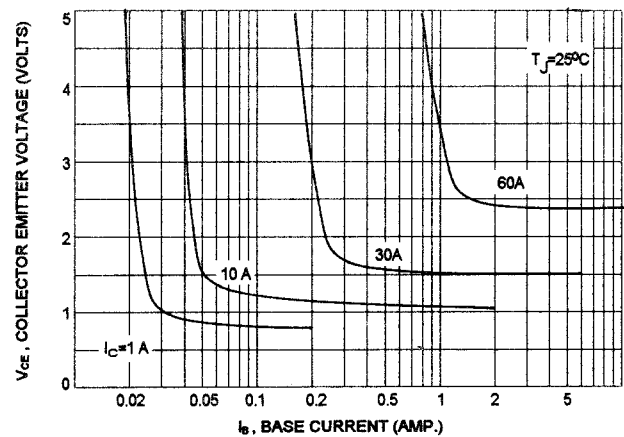
Delay Time	$V_{CC} = 175\text{ V}, I_C = 30\text{ A}$ $I_{B1} = 1.2\text{ A}, V_{BE(off)} = 5.0\text{ V}$ $t_p = 25\text{ us}, \text{Duty Cycle} \leq 2\%$	t_d		0.2	us
Rise Time		t_r		1.0	us
Storage Time		t_s		3.5	us
Fall Time		t_f		0.8	us

(1) Pulse Test: Pulse width = $300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$

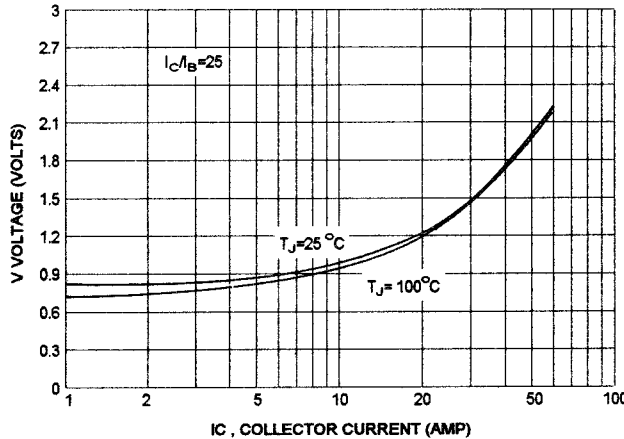
DC CURRENT GAIN



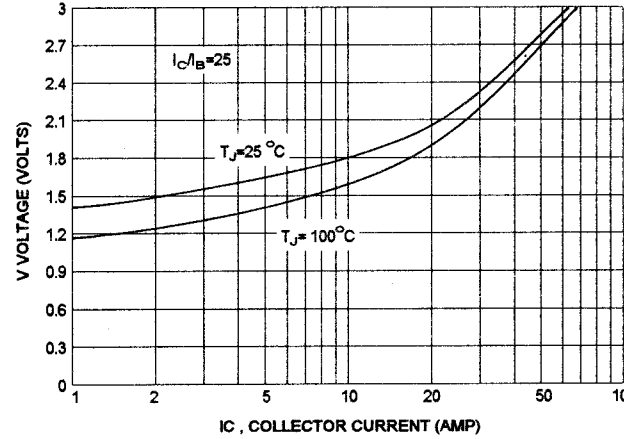
COLLECTOR SATURATION REGION



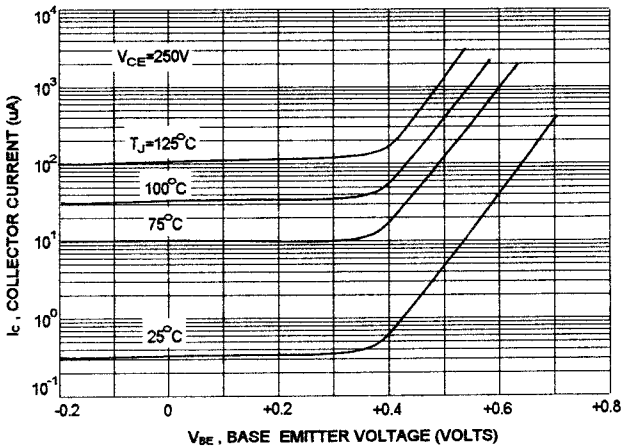
COLLECTOR-EMITTER SATURATION VOLTAGE



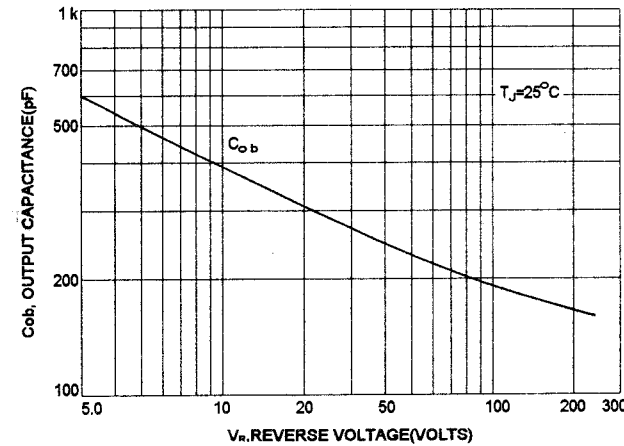
BASE-EMITTER VOLTAGE



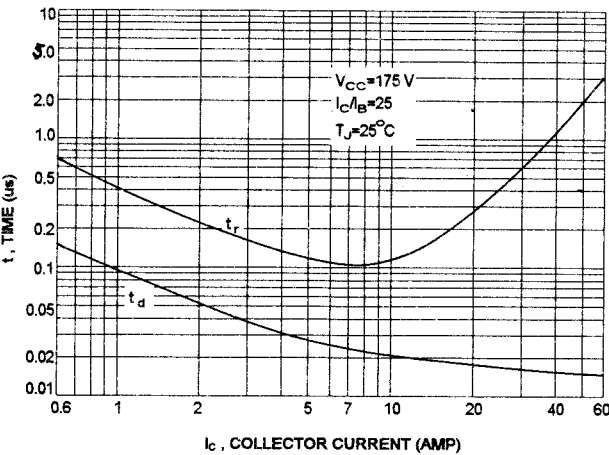
COLLECTOR CUT-OFF REGION



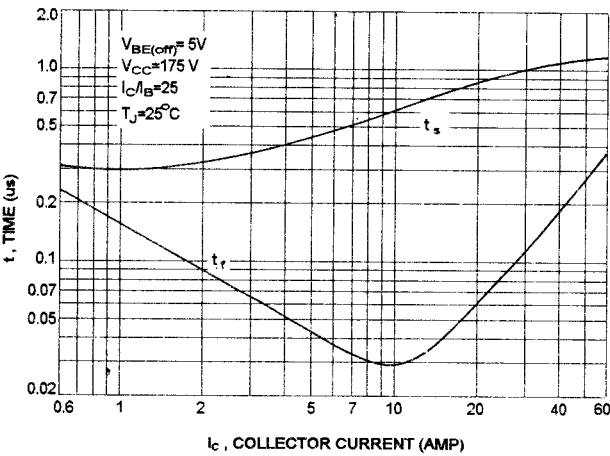
OUTPUT CAPACITANCES



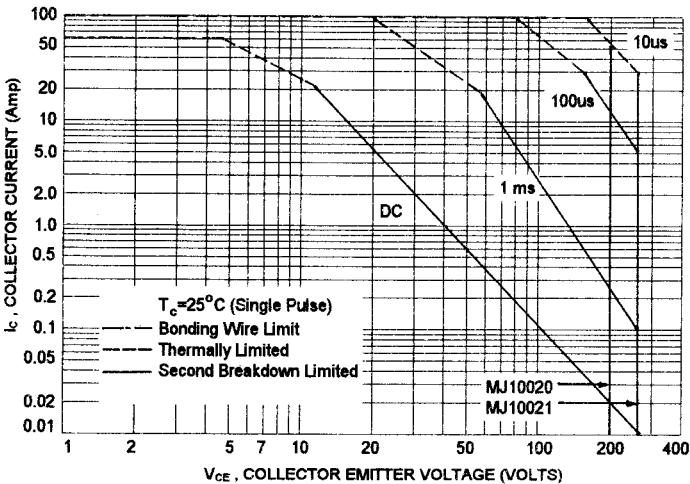
TURN-ON TIME



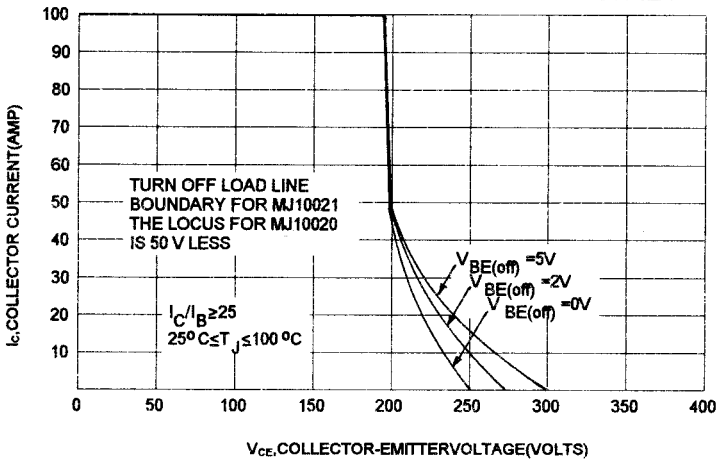
TURN-OFF TIME



ACTIVE REGION SAFE OPERATING AREA



REVERSE BIAS SWITCHING SAFE OPERATING AREA



Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life (atomic energy control, aeronautics , traffic control, combustion control, safety devices etc.)